

HMHA281, HMHA2801, HMHA2801A DC Input Half Pitch Mini-Flat Package 4-Pin Optocouplers®

Features

- Compact 4-pin package (2.4mm maximum standoff height)
- Half pitch leads for optimum board space savings
- Current Transfer Ratio:
HMHA2801: 80–600%
HMHA2801A: 80–160%
HMHA281: 50–600%
- Available in tape and reel quantities of 2500
- CSA (File #1201524), UL (File #E90700) and VDE (File #136480) certified

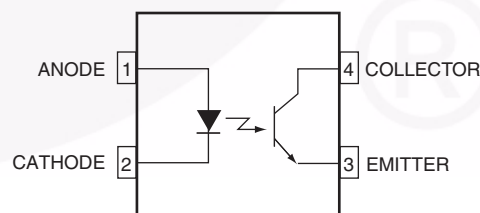
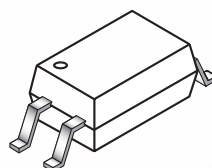
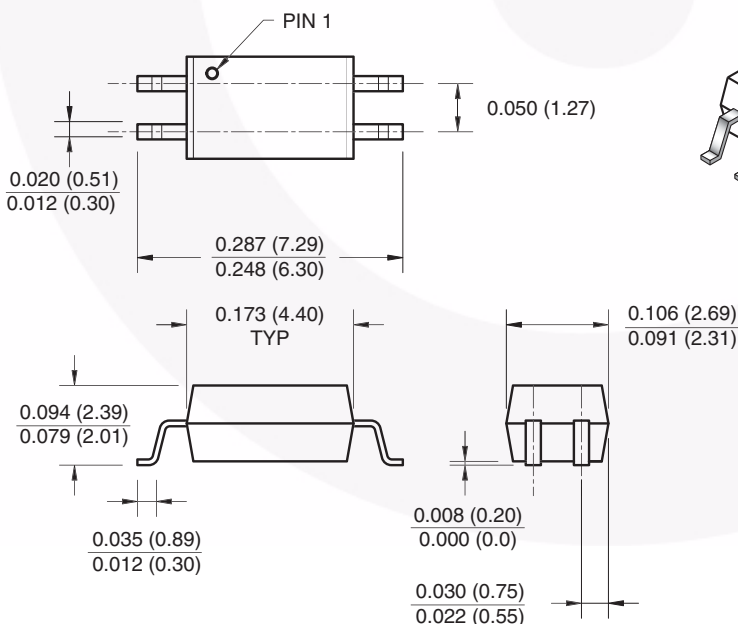
Applications

- Digital logic inputs
- Microprocessor inputs
- Power supply monitor
- Twisted pair line receiver
- Telephone line receiver

Description

The HMHA281, HMHA2801 and HMHA2801A devices consist of a gallium arsenide infrared emitting diode driving a silicon phototransistor in a compact 4-pin mini-flat package. The lead pitch is 1.27mm.

Package Dimensions



Equivalent Circuit

Note:

All dimensions are in inches (millimeters)

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Value	Units
TOTAL PACKAGE			
T_{STG}	Storage Temperature	-55 to +125	$^\circ\text{C}$
T_{OPR}	Operating Temperature	-55 to +100	$^\circ\text{C}$
EMITTER			
I_F (avg)	Continuous Forward Current	50	mA
I_F (pk)	Peak Forward Current (1 μs pulse, 300pps.)	1	A
V_R	Reverse Input Voltage	6	V
P_D	Power Dissipation	60	mW
	Derate linearly (above 25°C)	0.6	mW/ $^\circ\text{C}$
DETECTOR			
	Continuous Collector Current	50	mA
P_D	Power Dissipation	150	mW
	Derate linearly (above 25°C)	1.5	mW/ $^\circ\text{C}$
V_{CEO}	Collector-Emitter Voltage	80	V
V_{ECO}	Emitter-Collector Voltage	7	V

Electrical Characteristics ($T_A = 25^\circ\text{C}$)

Symbol	Parameter	Test Conditions	Device	Min.	Typ.*	Max.	Unit
INDIVIDUAL COMPONENT CHARACTERISTICS							
Emitter							
V _F	Forward Voltage	I _F = 10mA	All	1.0		1.3	V
I _R	Reverse Current	V _R = 5V	All			5	μA
Detector							
BV _{CEO}	Breakdown Voltage Collector to Emitter	I _C = 0.5mA, I _F = 0	All	80			V
BV _{ECO}	Emitter to Collector	I _E = 100μA, I _F = 0	All	7			
I _{CEO}	Collector Dark Current	V _{CE} = 80V, I _F = 0	All			100	nA
C _{CE}	Capacitance	V _{CE} = 0V, f = 1MHz	All		10		pF
TRANSFER CHARACTERISTICS							
CTR	DC Current Transfer Ratio	I _F = 5mA, V _{CE} = 5V	HMHA281	50		600	%
			HMHA2801	80		600	
			HMHA2801A	80		160	
V _{CE (SAT)}	Saturation Voltage	I _F = 8mA, I _C = 2.4mA	HMHA281			0.4	V
		I _F = 10mA, I _C = 2mA	HMHA2801			0.3	
			HMHA2801A			0.3	
t _r	Rise Time (Non-Saturated)	I _C = 2mA, V _{CE} = 5V, R _L = 100Ω	All		3		μs
t _f	Fall Time (Non-Saturated)	I _C = 2mA, V _{CE} = 5V, R _L = 100Ω	All		3		
ISOLATION CHARACTERISTICS							
V _{ISO}	Steady State Isolation Voltage	1 Minute	All	3750			VRMS

Typical Performance Characteristics

Fig. 1 Forward Current vs. Forward Voltage

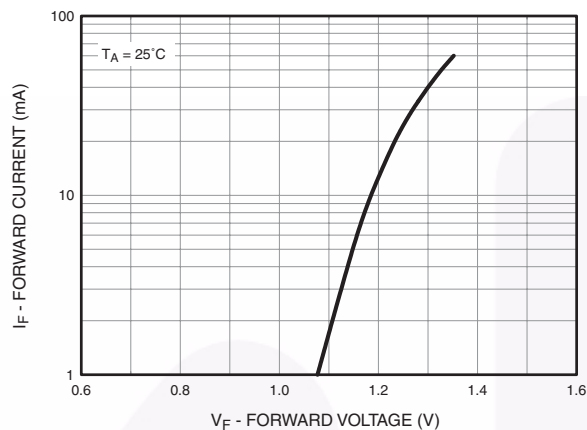


Fig. 2 Collector Current vs. Forward Current

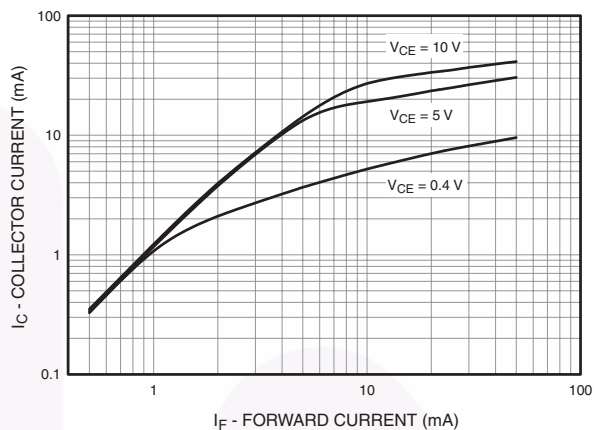


Fig. 3 Current Transfer Ratio vs. Forward Current

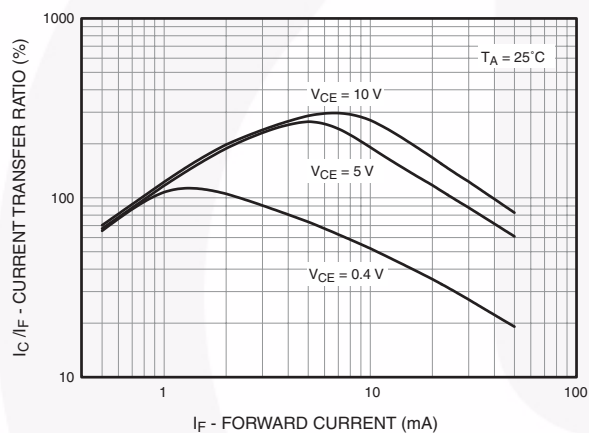


Fig. 4 Normalized CTR vs. Temperature

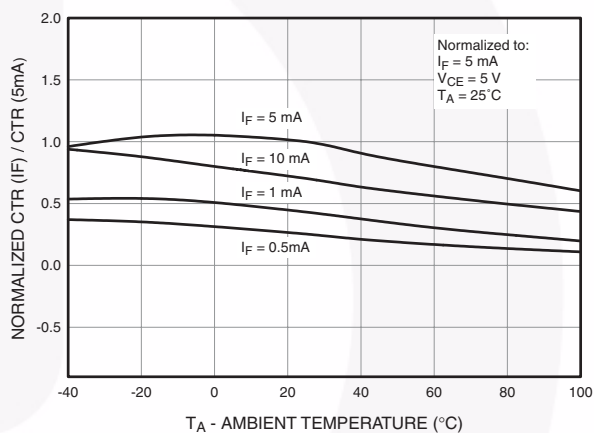
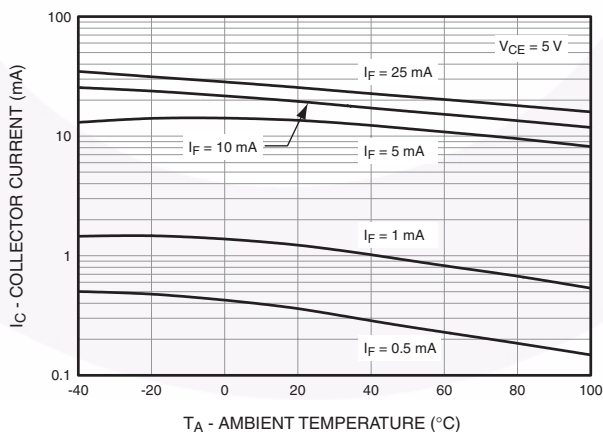


Fig. 5 Collector Current vs. Temperature



Typical Performance Characteristics (Continued)

Fig. 6 Collector Current vs. Collector-Emitter Voltage

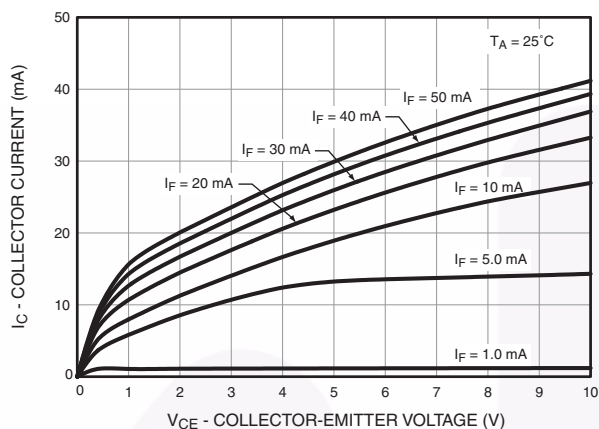


Fig. 7 Collector Current vs. Collector-Emitter Voltage

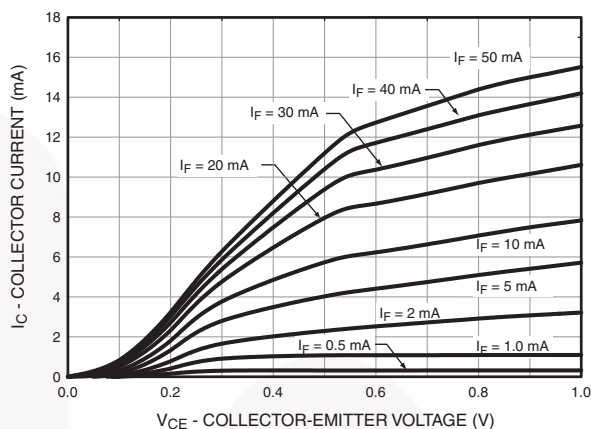


Fig. 8 Collector Dark Current vs. Temperature

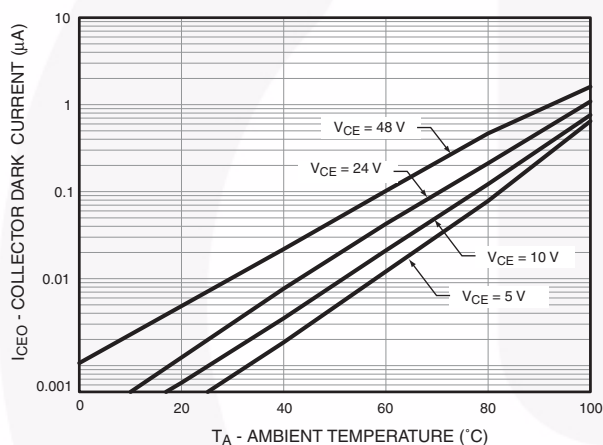


Fig. 9 Switching Time vs. Load Resistance

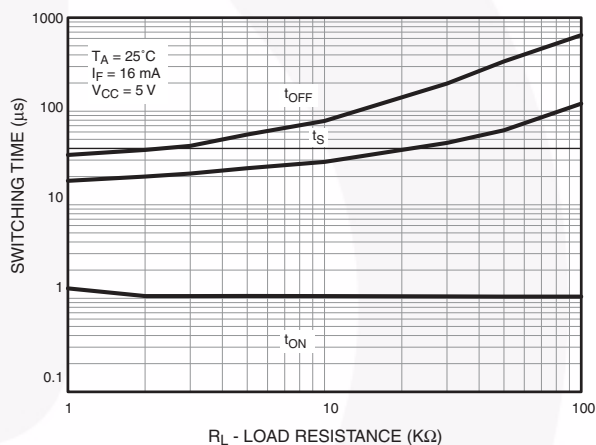
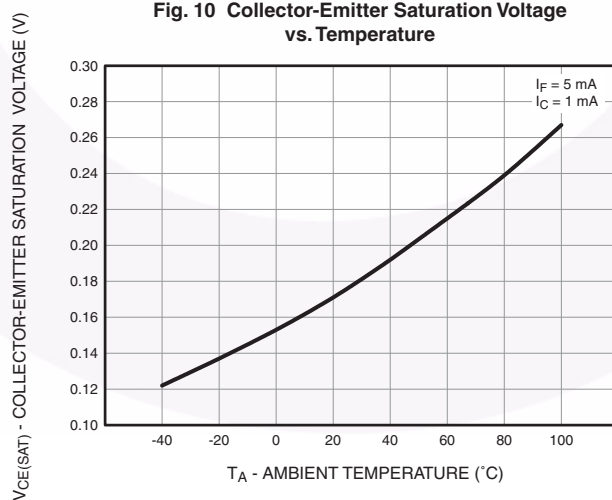


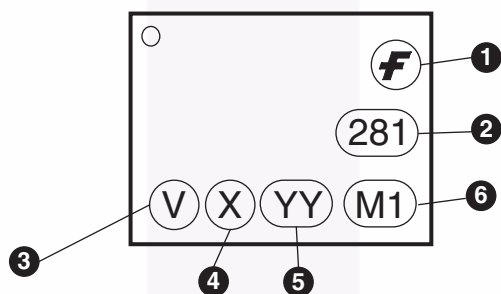
Fig. 10 Collector-Emitter Saturation Voltage vs. Temperature



Ordering Information

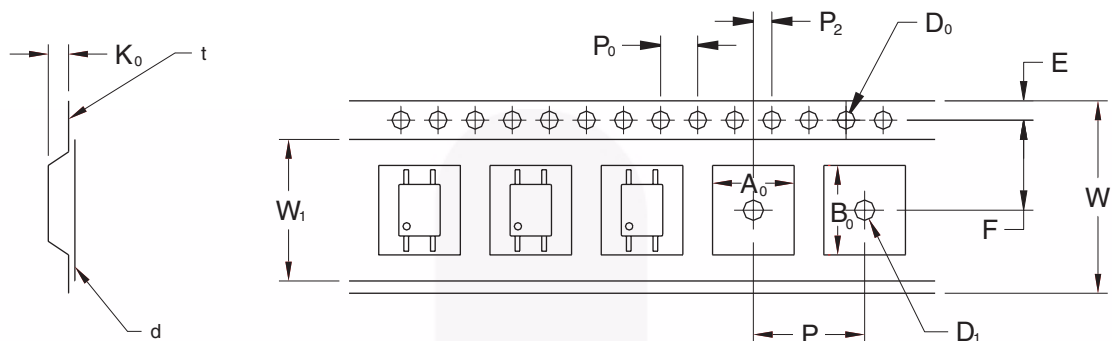
Option	Description
V	VDE Approved
R2	Tape and Reel (2500 units)
R2V	Tape and Reel (2500 units) and VDE Approved

Marking Information



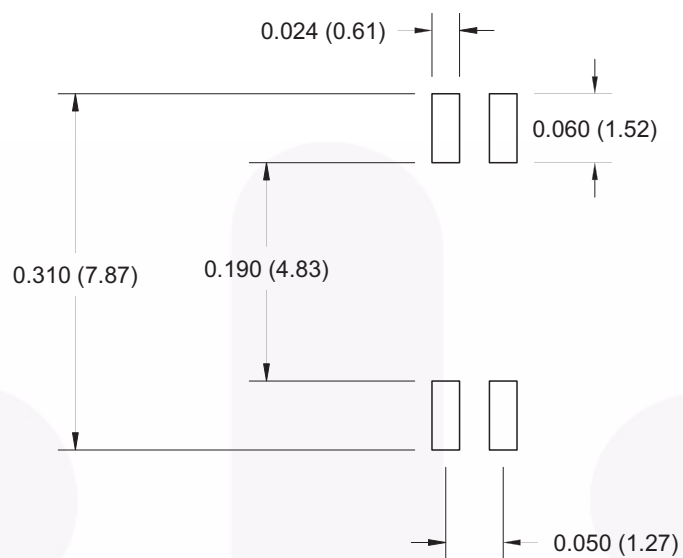
Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

Tape and Reel Dimensions

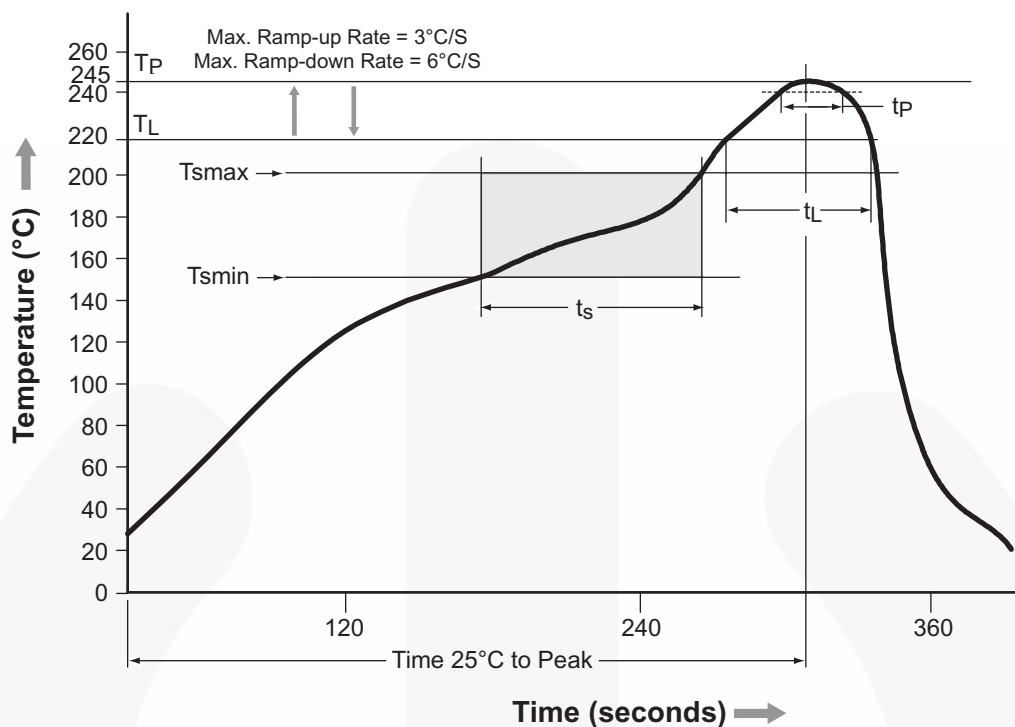


Description	Symbol	1.27 Pitch
		Dimensions (mm)
Tape Width	W	12.00 +0.30/-0.10
Tape Thickness	t	0.30 ±0.05
Sprocket Hole Pitch	P_0	4.00 ±0.10
Sprocket Hole Diameter	D_0	1.50 +0.10/-0.0
Sprocket Hole Location	E	1.75 ±0.10
Pocket Location	F	5.50 ±0.10
	P_2	2.00 ±0.10
Pocket Pitch	P	8.00 ±0.10
Pocket Dimension	A_0	2.80 ±0.10
	B_0	7.30 ±0.10
	K_0	2.30 ±0.10
Pocket Hole Diameter	D_1	1.50 Min.
Cover Tape Width	W_1	9.20
Cover Tape Thickness	d	0.065 ±0.010
Max. Component Rotation or Tilt		10° Max.
Devices Per Reel		2500
Reel Diameter		330mm (13")

Footprint Drawing for PCB Layout



Reflow Profile

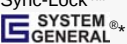


Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T _{smin})	150°C
Temperature Max. (T _{smax})	200°C
Time (t _s) from (T _{smin} to T _{smax})	60–120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60–150 seconds
Peak Body Package Temperature	245°C +0°C / –5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.



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Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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Rev. I54



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- Техническая поддержка проекта;
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